## **MIC914**

### 160MHz Low-Power SOT-23-5 Op Amp

# The Infinite Bandwidth Company™

### **General Description**

The MIC914 is a high-speed operational amplifier with a gain-bandwidth product of 160MHz. The part is unity gain stable provided its output is loaded with at least  $200\Omega$ . It has a very low 1.25mA supply current, and features the IttyBitty SOT-23-5 package.

Supply voltage range is from  $\pm 2.5 \text{V}$  to  $\pm 9 \text{V}$ , allowing the MIC914 to be used in low-voltage circuits or applications requiring large dynamic range.

The MIC914 is stable driving any capacitative load and achieves excellent PSRR and CMRR, making it much easier to use than most conventional high-speed devices. Low supply voltage, low power consumption, and small packing make the MIC914 ideal for portable equipment. The ability to drive capacitative loads also makes it possible to drive long coaxial cables.

#### **Features**

- 160MHz gain bandwidth product
- 1.25mA supply current
- SOT-23-5 package
- 160V/µs slew rate
- drives any capacitive load
- 112dB CMRR

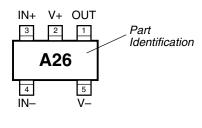
## **Applications**

- Video
- Imaging
- Ultrasound
- Portable equipment
- · Line drivers
- XDSL

### **Ordering Information**

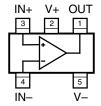
Part Number	Junction Temp. Range	Package		
MIC914BM5	–40°C to +85°C	SOT-23-5		

## **Pin Configuration**



SOT-23-5

### **Functional Pinout**



SOT-23-5

## **Pin Description**

Pin Number	Pin Name	Pin Function
1	OUT	Output: Amplifier Output
2	V+	Positive Supply (Input)
3	IN+	Noninverting Input
4	IN-	Inverting Input
5	V-	Negative Supply (Input)

# **Absolute Maximum Ratings (Note 1)**

Supply Voltage (V <sub>V+</sub> – V <sub>V</sub> _)	20V
Differentail Input Voltage ( V <sub>IN+</sub> - V <sub>IN-</sub>  )	4V, <b>Note 3</b>
Input Common-Mode Range (V <sub>IN+</sub> , V <sub>IN-</sub> )	V <sub>V+</sub> to V <sub>V-</sub>
Lead Temperature (soldering, 5 sec.)	260°C
Storage Temperature (T <sub>S</sub> )	150°C
ESD Rating, Note 4	1.5kV

# **Operating Ratings (Note 2)**

Supply Voltage (V <sub>S</sub> )	±2.5V to ±9V
Junction Temperature (T <sub>J</sub> )	40°C to +85°C
Package Thermal Resistance	260°C/W

## **Electrical Characteristics (±5V)**

 $V_{V+} = +5V, \ V_{V-} = -5V, \ V_{CM} = 0V, \ V_{OUT} = 0V; \ R_L = 10M\Omega; \ T_J = 25^{\circ}C, \ \textbf{bold} \ \ \text{values indicate} \ -40^{\circ}C \leq T_J \leq +85^{\circ}C; \ unless \ noted.$ 

Symbol	Parameter	Condition	Min	Тур	Max	Units
$\overline{V_{OS}}$	Input Offset Voltage			1	10	mV
V <sub>OS</sub>	Input Offset Voltage Temperature Coefficient			4		μV/°C
I <sub>B</sub>	Input Bias Current			1.5	4 <b>8</b>	μ <b>Α</b> μ <b>Α</b>
I <sub>os</sub>	Input Offset Current			0.03	2 <b>3</b>	μ <b>Α</b> μ <b>Α</b>
$V_{CM}$	Input Common-Mode Range	CMRR > 60dB	-3.5		+3.5	V
CMRR	Common-Mode Rejection Ratio	-3V < V <sub>CM</sub> < +3V	80	110		dB
PSRR	Power Supply Rejection Ratio	±5V < V <sub>S</sub> < ±9V	75	88		dB
$\overline{A_{VOL}}$	Large-Signal Voltage Gain	$R_L = 2k$ , $V_{OUT} = \pm 2V$	65	78		dB
		$R_L = 200\Omega$ , $V_{OUT} = \pm 1V$	65	78		dB
V <sub>OUT</sub>	Maximum Output Voltage Swing	positive, $R_L = 2k\Omega$	+3.3 + <b>3.0</b>	3.5		V
		negative, $R_L = 2k\Omega$		-3.5	-3.3 - <b>3.0</b>	V V
		positive, $R_L = 200\Omega$	+2.8 <b>+2.5</b>	3.2		V V
		negative, $R_L = 200\Omega$ , <b>Note 5</b>		-2.5	-1.7 - <b>1.0</b>	V V
		negative, $R_L = 200\Omega$ , $25^{\circ}C \le T_J \le +85^{\circ}C$ , Note 5			-1.7	V
GBW	Unity Gain-Bandwidth Product	$R_L = 1k\Omega$		135		MHz
BW	-3dB Bandwidth	$A_V = 2, R_L = 470\Omega$		155		MHz
SR	Slew Rate			135		V/µs
I <sub>GND</sub>	Short-Circuit Output Current	source		65		mA
GND		sink		17		mA
I <sub>GND</sub>	Supply Current			1.25	1.8 <b>2.3</b>	mA mA

## **Electrical Characteristics**

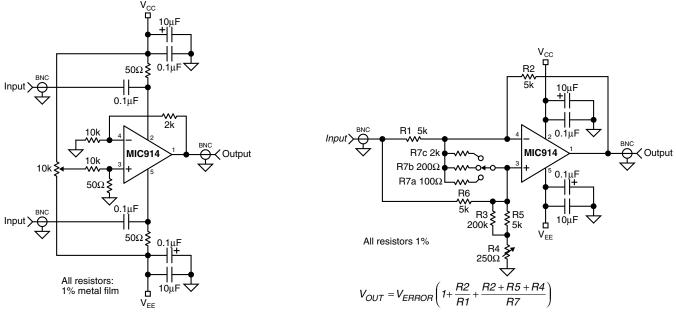
 $V_{V+} = +9V, \ V_{V-} = -9V, \ V_{CM} = 0V, \ V_{OUT} = 0V; \ R_L = 10M\Omega; \ T_J = 25^{\circ}C, \ \textbf{bold} \ values \ indicate} \ -40^{\circ}C \leq T_J \leq +85^{\circ}C; \ unless \ noted$ 

Symbol	Parameter	Condition	Min	Тур	Max	Units
V <sub>OS</sub>	Input Offset Voltage			1	10	mV
V <sub>OS</sub>	Input Offset Voltage Temperature Coefficient			4		μV/°C
I <sub>B</sub>	Input Bias Current			1.5	4 <b>8</b>	μ <b>Α</b> μ <b>Α</b>

Symbol	Parameter	Condition	Min	Тур	Max	Units
I <sub>OS</sub>	Input Offset Current			0.03	2 <b>3</b>	μ <b>Α</b> μ <b>Α</b>
$V_{CM}$	Input Common-Mode Range	CMRR > 60dB	-7.5		+7.5	V
CMRR	Common-Mode Rejection Ratio	-7V < V <sub>CM</sub> < 7V	80	112		dB
$\overline{A_{VOL}}$	Large-Signal Voltage Gain	$R_L = 2k\Omega, V_{OUT} = \pm 6V$	65	80		dB
V <sub>OUT</sub>	Maximum Output Voltage Swing	positive, $R_L = 2k\Omega$	+7.2 +6.8	+7.4		V V
		negative, $R_L = 2k\Omega$		-7.4	−7.2 <b>−6.8</b>	V
GBW	Gain-Bandwidth Product	$R_L = 1k\Omega$		160		MHz
BW	-3dB Bandwidth	$A_V = 2, R_L = 470\Omega$		185		MHz
SR	Slew Rate			160		V/µs
I <sub>GND</sub>	Short-Circuit Output Current	source		80		mA
		sink		22		mA
I <sub>GND</sub>	Supply Current			1.35	1.9 <b>2.4</b>	mA mA

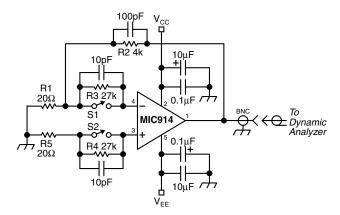
- Note 1. Exceeding the absolute maximum rating may damage the device.
- Note 2. The device is not guaranteed to function outside its operating rating.
- **Note 3.** Exceeding the maximum differential input voltage will damage the input stage and degrade performance (in particular, input bias current is likely to change).
- Note 4. Devices are ESD sensitive. Handling precautions recommended. Human body model, 1.5k in series with 100pF.
- Note 5. Output swing limited by the maximum output sink capability, refer to the short-circuit current vs. temperature graph in "Typical Characteristics."

# **Test Circuits**



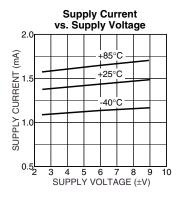
**PSRR vs. Frequency** 

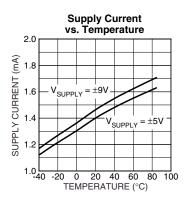
**CMRR vs. Frequency** 

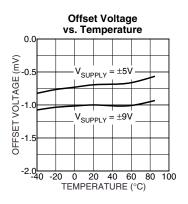


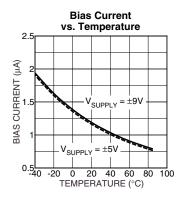
**Noise Measurement** 

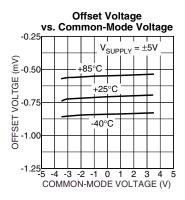
#### **Electrical Characteristics**

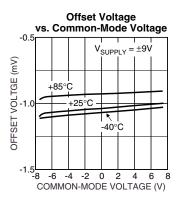


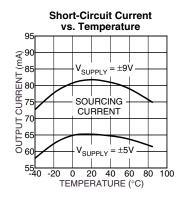


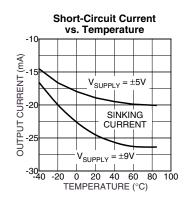


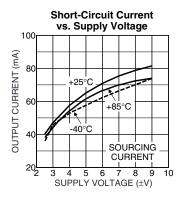


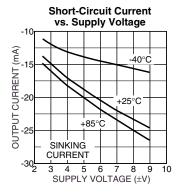


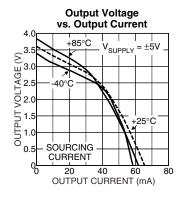


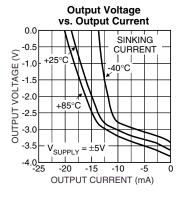


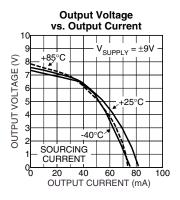


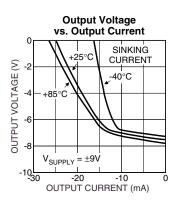


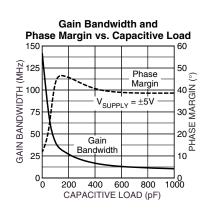


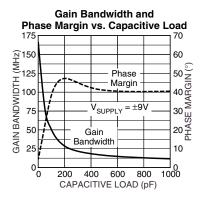


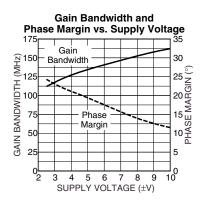


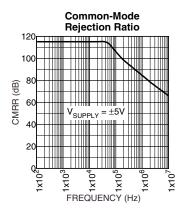


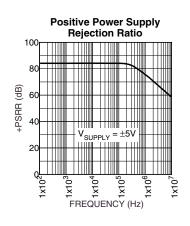


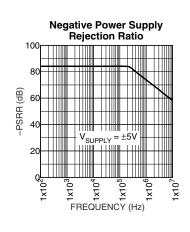


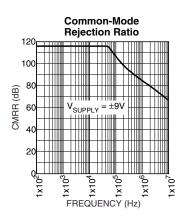


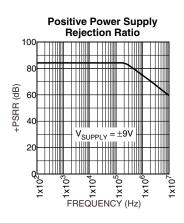


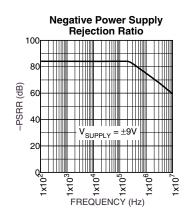


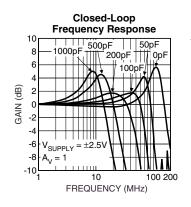


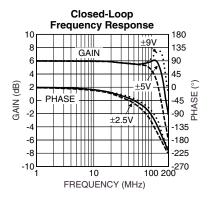


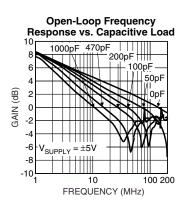


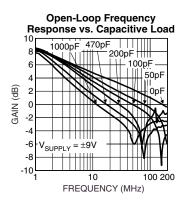


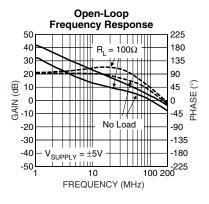


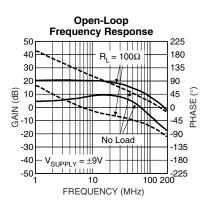


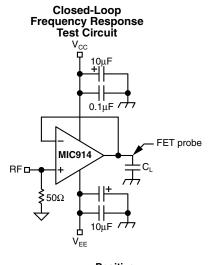


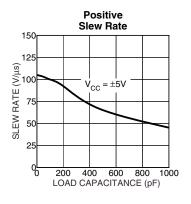


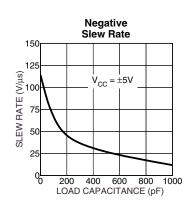


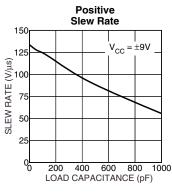


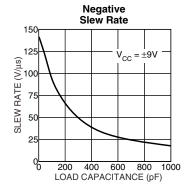


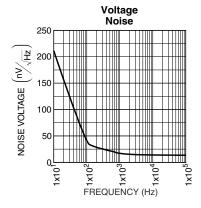


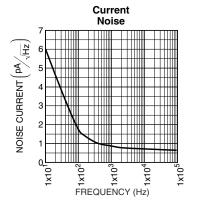


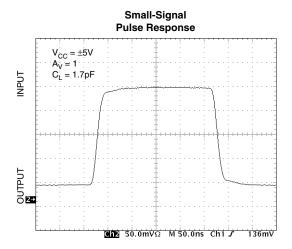


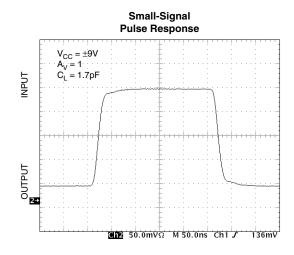


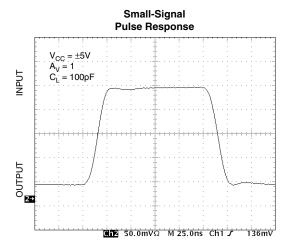


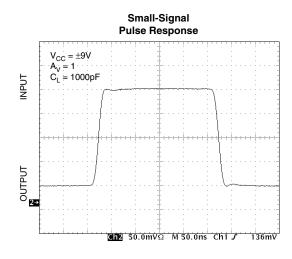


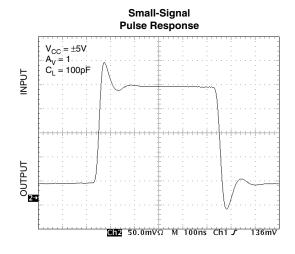


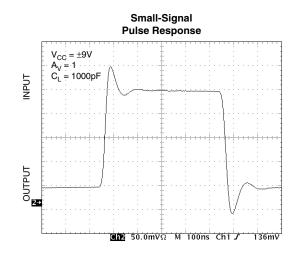


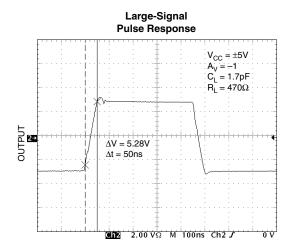


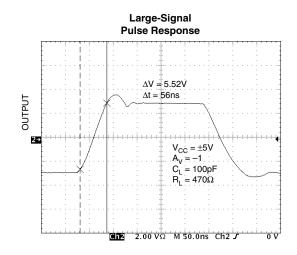


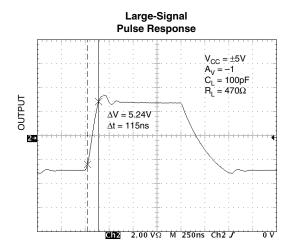


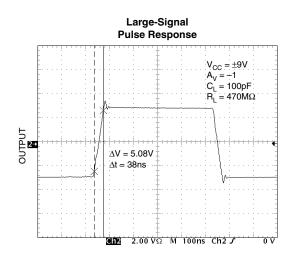


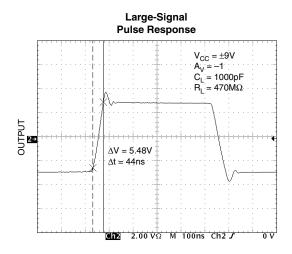


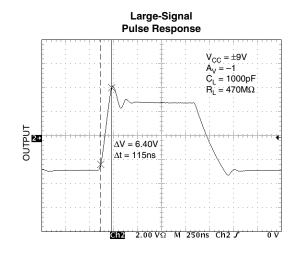












### **Applications Information**

The MIC914 is a high-speed, voltage-feedback operational amplifier featuring very low supply current and excellent stability. This device is unity gain stable with  $R_L \leq 200\Omega$  and capable of driving high capacitance loads.

#### **Stability Considerations**

The MIC914 is unity gain stable and it is capable of driving unlimited capacitance loads, but some design considerations are required to ensure stability. The output needs to be loaded with  $200\Omega$  resistance or less and/or have sufficient load capacitance to achieve stability (refer to the "Load Capacitance vs. Phase Margin" graph).

For applications requiring a little less speed, Micrel offers the MIC911, a more heavily compensated version of the MIC914 which provides extremely stable operation for all load resistance and capacitance.

For stability considerations at different supply voltages, please refer to the graph elsewhere in the datasheet entitled "Gain Bandwidth and Phase Margin vs. Supply Voltage".

#### **Driving High Capacitance**

The MIC914 is stable when driving high capacitance (see "Typical Characteristics: Gain Bandwidth and Phase Margin vs. Load Capacitance") making it ideal for driving long coaxial cables or other high-capacitance loads.

Phase margin remains constant as load capacitance is increased. Most high-speed op amps are only able to drive limited capacitance.

Note: increasing load capacitance does reduce the speed of the device (see "Typical Characteristics: Gain Bandwidth and Phase Margin vs. Load"). In applications where the load capacitance reduces the speed of the op amp to an unacceptable level, the effect of the load capacitance can be reduced by adding a small resistor  $(<100\Omega)$  in series with the output.

#### **Feedback Resistor Selection**

Conventional op amp gain configurations and resistor selection apply, the MIC914 is NOT a current feedback device.

Also, for minimum peaking, the feedback resistor should have low parasitic capacitance, usually  $470\Omega$  is ideal. To use the part as a follower, the output should be connected to input via a short wire.

#### **Layout Considerations**

All high speed devices require careful PCB layout. The following guidelines should be observed: Capacitance, particularly on the two inputs pins will degrade performance; avoid large copper traces to the inputs. Keep the output signal away from the inputs and use a ground plane.

It is important to ensure adequate supply bypassing capacitors are located close to the device.

#### **Power Supply Bypassing**

Regular supply bypassing techniques are recommended. A  $10\mu F$  capacitor in parallel with a  $0.1\mu F$  capacitor on both the positive and negative supplies are ideal. For best performance all bypassing capacitors should be located as close to the op amp as possible and all capacitors should be low ESL (equivalent series inductance), ESR (equivalent series resistance). Surface-mount ceramic capacitors are ideal.

#### **Thermal Considerations**

The SOT-23-5 package, like all small packages, has a high thermal resistance. It is important to ensure the IC does not exceed the maximum operating junction (die) temperature of 85°C. The part can be operated up to the absolute maximum temperature rating of 125°C, but between 85°C and 125°C performance will degrade, in particular CMRR will reduce.

An MIC914 with no load, dissipates power equal to the quiescent supply current \* supply voltage

$$P_{D(noload)} = (V_{V+} - V_{V-})I_S$$

When a load is added, the additional power is dissipated in the output stage of the op amp. The power dissipated in the device is a function of supply voltage, output voltage and output current.

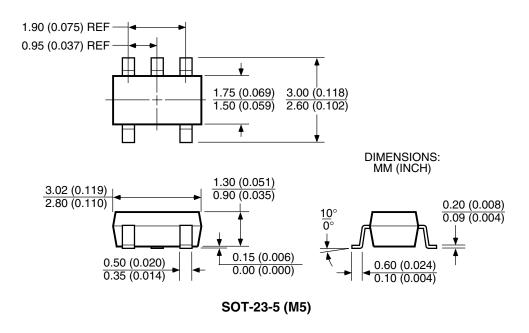
$$P_{D(output \, stage)} = (V_{V+} - V_{OUT})I_{OUT}$$

Total Power Dissipation = 
$$P_{D(no load)} + P_{D(output stage)}$$

Ensure the total power dissipated in the device is no greater than the thermal capacity of the package. The SOT23-5 package has a thermal resistance of 260°C/W.

Max. Allowable Power Dissipation = 
$$\frac{T_{J(max)} - T_{A(max)}}{260W}$$

# **Package Information**



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